TOSHIBA Photocoupler Photorelay

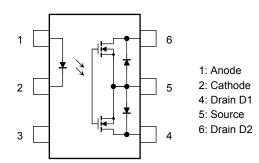
# TLP592A

Telecommunications
Measurement and Control Equipment
Data Acquisition System
Measurement Equipment

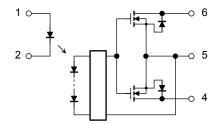
The Toshiba TLP592A consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a 6-pin DIP package. This photorelay has higher output current rating than phototransistor-type photocoupler; hence, it is suitable for use as On/Off control for high current.

- Normally open (1-form-A) device
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 500 mA (max)
- On-state resistance:  $2 \Omega$  (max)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1557, File No.E67349

### Pin Configuration (top view)



#### **Schematic**



Unit: mm

5 5 4 5 7 62 ± 0.25

1 2 3 7.62 ± 0.25

2.54 ± 0.25

2.54 ± 0.25

JEDEC —

JEITA —

11-7A8

Weight: 0.4 g (typ.)

**TOSHIBA** 

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
	Forward current		lF	50	mA	
	Forward current derating (Ta ≧ 25°C)		ΔI <sub>F</sub> /°C	-0.5	mA/°C	
LED	Peak forward (100 μs puls		I <sub>FP</sub>	1	Α	
	Reverse volt	age	V <sub>R</sub>	5	V	
	Junction tem	perature	Tj	125	°C	
	Off-state output terminal voltage		V <sub>OFF</sub>	60	V	
	On-state current	A connection	I <sub>ON</sub>	500		
		B connection		500	mA	
Detector		C connection		1000		
	Forward current derating (Ta ≥ 25°C)	A connection		-5.0		
		B connection	∆lon/°C	-5.0	mA/°C	
		C connection		-10.0		
	Junction temperature		Tj	125	°C	
Storage temperature		T <sub>stg</sub>	-55 to 125	°C		
Operating temperature			T <sub>opr</sub>	-40 to 85	°C	
Lead soldering temperature (10 s)			T <sub>sol</sub>	260	°C	
Isolation voltage (AC, 1 min, R.H. ≦ 60%) (Note 1)			BVS	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

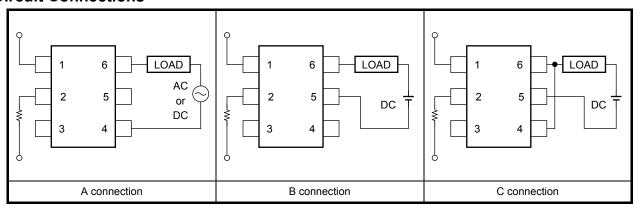
Note 1: LED pins are shorted together. Detector pins are also shorted together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	48	V
Forward current	l <sub>F</sub>	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	500	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



2

### **Electrical Characteristics Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	$V_{F}$	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse voltage	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μА
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	loff	V <sub>OFF</sub> = 60 V	_	_	1	μΑ
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	130	_	pF

### **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 500 mA	_	1.6	3	mA
Return LED current		I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
	A connection	R <sub>ON</sub>	I <sub>ON</sub> = 500 mA, I <sub>F</sub> = 5 mA	_	1	2	
On-state resistance	B connection		I <sub>ON</sub> = 500 mA, I <sub>F</sub> = 5 mA	_	0.5	1	Ω
	C connection		I <sub>ON</sub> = 1000 mA, I <sub>F</sub> = 5 mA	_	0.25	_	

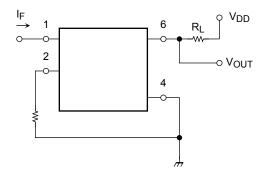
## Isolation Characteristics (Ta = 25°C)

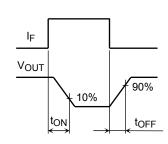
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≦ 60%	$5 \times 10^{10}$	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	
		DC, 1 min, in oil	_	5000	_	Vdc

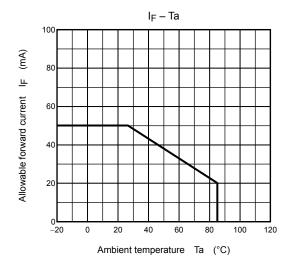
### **Switching Characteristics (Ta = 25°C)**

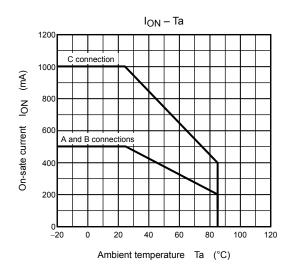
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	$R_L = 200 \Omega$ (Note 2)	_	8.0	2	ms
Turn-off time	toff	V <sub>DD</sub> = 20 V, I <sub>F</sub> = 5 mA	_	0.1	0.5	1115

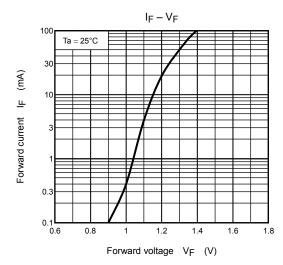
Note 2: Switching time test circuit

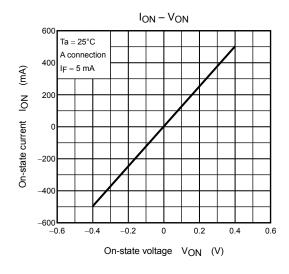


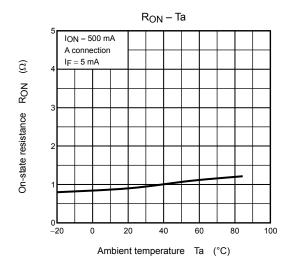


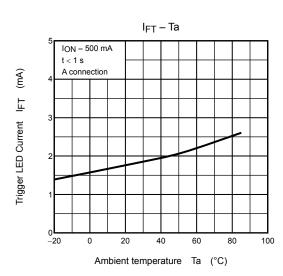


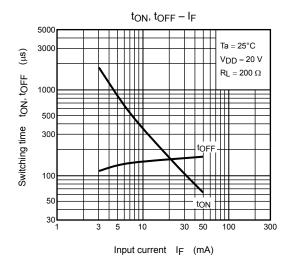


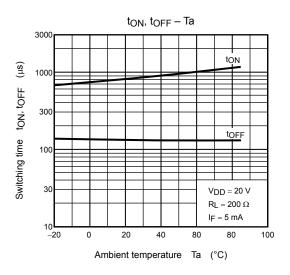


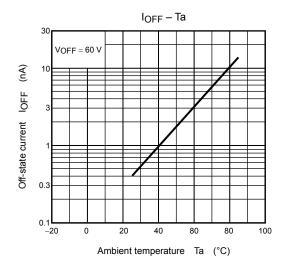












5 2007-10-01

#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
  may result from its use. No license is granted by implication or otherwise under any patents or other rights of
  TOSHIBA or the third parties.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
  compatibility. Please use these products in this document in compliance with all applicable laws and regulations
  that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
  occurring as a result of noncompliance with applicable laws and regulations.